Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- · Low threshold voltage
- Trench MOSFET technology
- Side wettable flanks for optical solder inspection
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- · Exposed drain pad for excellent thermal conduction

3. Applications

- Charging switch for portable devices
- DC-to-DC converters
- · Power management in battery-driven portable devices
- · Hard disk and computing power management

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-12	V
V_{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-15	Α
Static characteristics							
R _{DSon}	drain-source on-state resistance	$V_{GS} = -4.5 \text{ V}; I_D = -10 \text{ A}; T_j = 25 \text{ °C}$		-	10	11.5	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain	1 1 1 1 6	D I
2	D	drain		
3	G	gate	2 5	G (F)
4	S	source	3 8 4	s
5	D	drain	Transparent top view	017aaa257
6	D	drain	DFN2020MD-6 (SOT1220)	
7	D	drain		
8	S	source		

6. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
PMPB10UP		plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); 6 terminals; 0.65 mm pitch; 2 mm x 2 mm x 0.65 mm body	SOT1220				

7. Marking

Table 4. Marking codes

Type number	Marking code
PMPB10UP	6G

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-12	V
V_{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-15	А
		V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-10	А
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-6.3	А
I _{DM}	peak drain current	T_{amb} = 25 °C; pulsed; $t_p \le 10 \mu s$		-	-40	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1]	-	1.7	W
		T _{amb} = 25 °C; t ≤ 5 s	[1]	-	3.5	W
		T _{sp} = 25 °C		-	13	W
T _j	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	diode		'		'	'
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.6	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

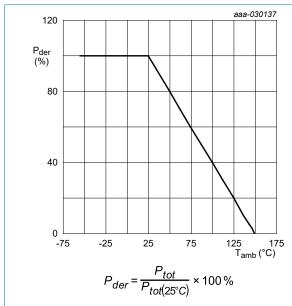


Fig. 1. Normalized total power dissipation as a function of ambient temperature

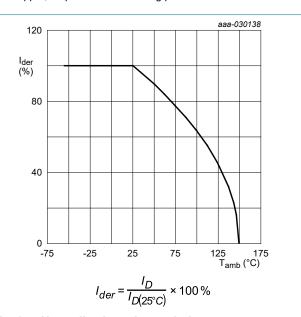


Fig. 2. Normalized continous drain current as a function of ambient temperature

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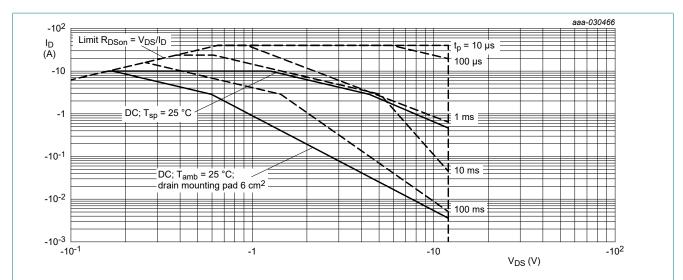


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	235	270	K/W
	junction to ambient		[2]	-	67	74	K/W
		in free air, t ≤ 5 s	[2]	-	33	36	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	5	10	K/W

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

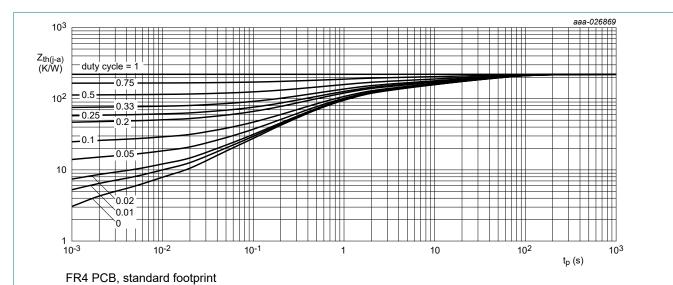


Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

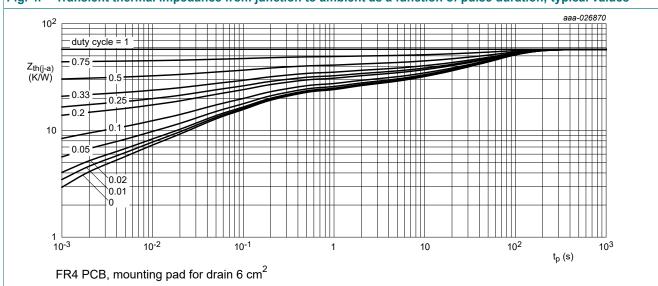


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 μ A; V_{GS} = 0 V; T_j = 25 °C	-12	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = -250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	0.47	0.7	0.9	V
I _{DSS}	drain leakage current	$V_{DS} = -12 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-1	μΑ
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
R _{DSon}	drain-source on-state	$V_{GS} = -4.5 \text{ V}; I_D = -10 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	10	11.5	mΩ
	resistance	V _{GS} = -4.5 V; I _D = -10 A; T _j = 150 °C	-	14	16	mΩ
		$V_{GS} = -2.5 \text{ V}; I_D = -6 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	12	15.5	mΩ
		V _{GS} = -1.8 V; I _D = -4 A; T _j = 25 °C	-	17	22	mΩ
9 _{fs}	forward transconductance	$V_{DS} = -10 \text{ V}; I_D = -10 \text{ A}; T_j = 25 \text{ °C}$	-	42	-	S
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	-	13.2	-	Ω
Dynamic ch	aracteristics		·	•		
Q _{G(tot)}	total gate charge	$V_{DS} = -6 \text{ V}; I_D = -10 \text{ A}; V_{GS} = -4.5 \text{ V};$	-	27	40	nC
Q_{GS}	gate-source charge	T _j = 25 °C	-	3.4	-	nC
Q_{GD}	gate-drain charge		-	7.6	-	nC
C _{iss}	input capacitance	V _{DS} = -6 V; f = 1 MHz; V _{GS} = 0 V;	-	2200	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	509	-	pF
C _{rss}	reverse transfer capacitance		-	454	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = -6 \text{ V}; I_D = -10 \text{ A}; V_{GS} = -4.5 \text{ V};$	-	4	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	15	-	ns
t _{d(off)}	turn-off delay time		-	149	-	ns
t _f	fall time		-	100	-	ns
Source-drai	n diode		•			
V_{SD}	source-drain voltage	$I_S = -1.6 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-0.6	-1.2	V

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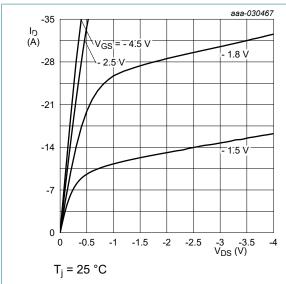


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

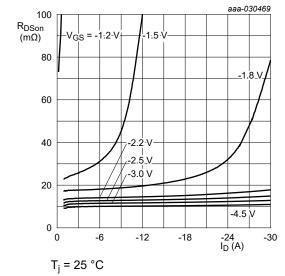


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

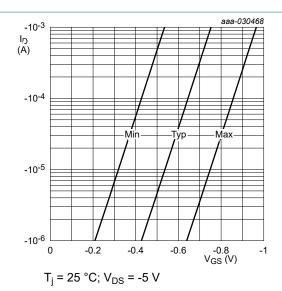


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

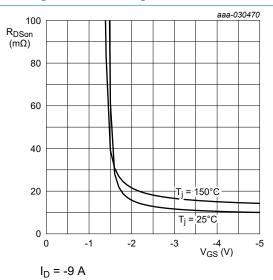


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

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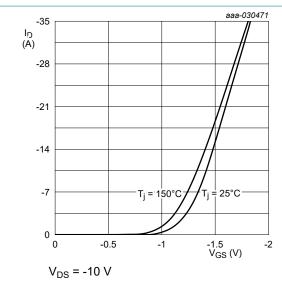


Fig. 10. Transfer characteristics; drain current as a function of gate-source voltage; typical values

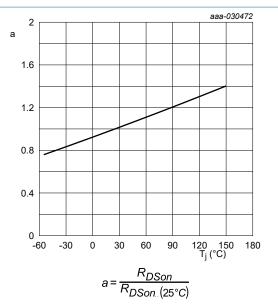


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature; typical values

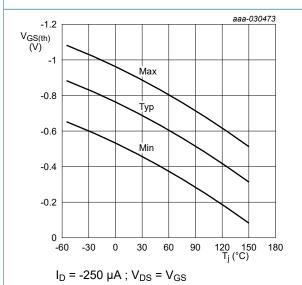
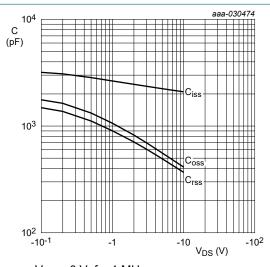


Fig. 12. Gate-source threshold voltage as a function of junction temperature



 $V_{GS} = 0 V$; f = 1 MHz

Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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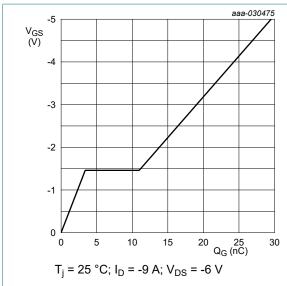


Fig. 14. Gate-source voltage as a function of gate charge; typical values

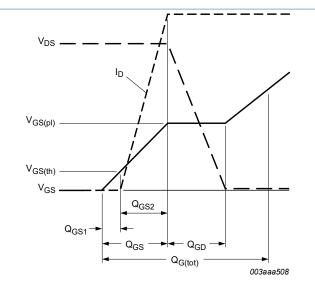


Fig. 15. Gate charge waveform definitions

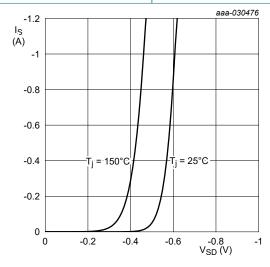
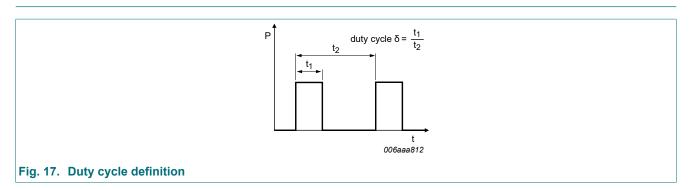


Fig. 16. Source current as a function of source-drain voltage; typical values

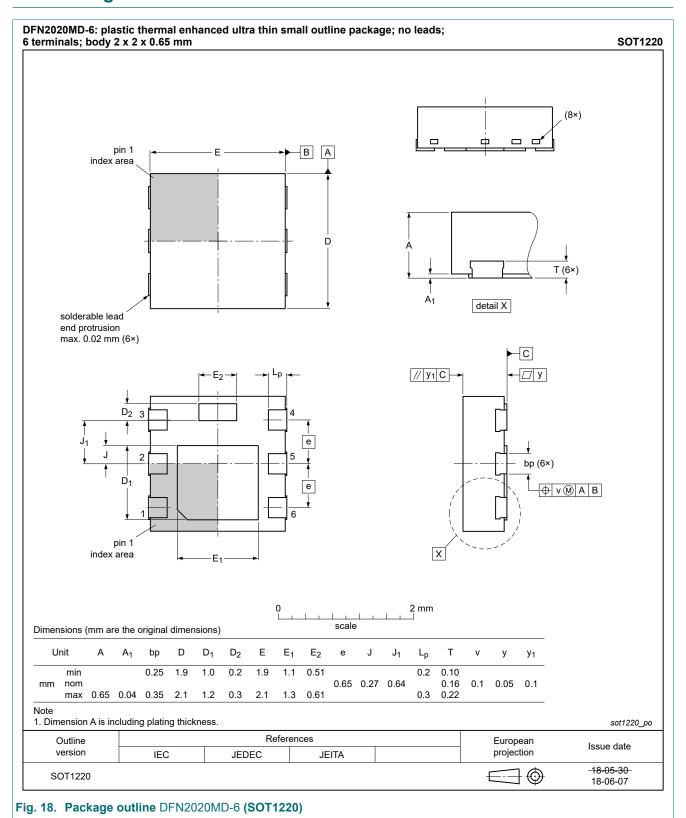
11. Test information

 $V_{GS} = 0 V$



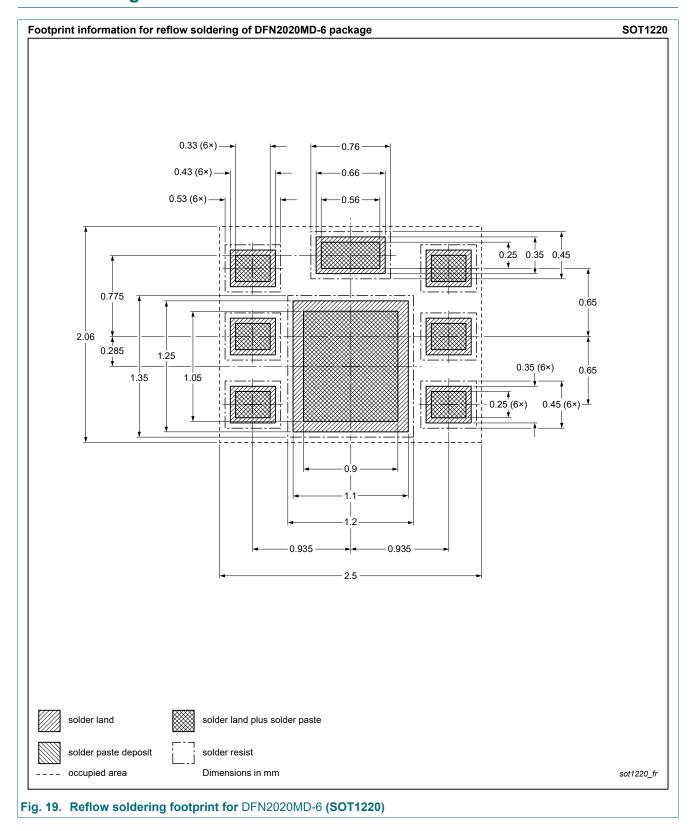
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12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMPB10UP v.3	20201005	Product data sheet	-	PMPB10UP v.2			
Modifications:	Limiting values: Fig.	Limiting values: Fig. 3. Safe operating area; curves revised.					
PMPB10UP v.2	20200124	Product data sheet	-	PMPB10UP v.1			
PMPB10UP v.1	20191216	Product data sheet	-	-			

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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